

# 650V SiC Schottky Diode

# Amp+<sup>™</sup> Features

- Unipolar rectifier with surge current
- Zero reverse recovery current
- · Fast, temperature-independent switching
- Avalanche tested to 67mJ per leg\*

## Amp+<sup>™</sup> Benefits

- Zero switching loss
- Higher efficiency
- Smaller heat sink
- Easy to parallel

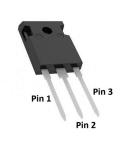
# Amp+<sup>™</sup> Applications

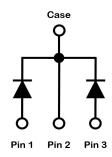
- General Purpose
- · Switched mode power supplies, UPS
- Power factor correction
- Output rectification

# GP3D020A065U

VDC	650 V
Qc	52 nC***
I <sub>F</sub>	20 A***
T <sub>j</sub> ,max	175 °C

### Package





Part #	Package	Marking
GP3D020A065U	TO-247-3L	3D020A065



### Maximum Ratings, at T<sub>i</sub>=25 °C, unless otherwise specified

Characteristics Per Leg	Symbol	Conditions	Values	Unit	
		T <sub>C</sub> =25 °C, T <sub>j</sub> =175 °C	28		
Continuous forward current	۱ <sub>F</sub> **	T <sub>C</sub> =125 °C, T <sub>j</sub> =175 °C	15	A	
		T <sub>C</sub> =150 °C, T <sub>j</sub> =175 °C	9		
Surge non-repetitive forward current	1	T <sub>C</sub> =25 °C, t <sub>p</sub> =8.3 ms	80	•	
sine halfwave	I <sub>FSM</sub>	T <sub>C</sub> =110 °C, t <sub>p</sub> =8.3 ms	70	— A	
Non-repetitive peak forward current	I <sub>F,max</sub>	T <sub>C</sub> =25 °C, t <sub>p</sub> =10 μs	575	A	
<i>i<sup>2</sup>t</i> value	∫i²dt	T <sub>C</sub> =25 °C, t <sub>p</sub> =8.3 ms	27	A <sup>2</sup> s	
		T <sub>C</sub> =110 °C, t <sub>p</sub> =8.3 ms	20		
Repetitive peak reverse voltage	V <sub>RRM</sub>	T <sub>j</sub> =25 °C	650	V	
Diode <i>dv/dt</i> ruggedness	dv/dt	Turn-on slew rate, repetitive	200	V/ns	
Power dissipation	P <sub>tot</sub> **	T <sub>C</sub> =25 °C	97	W	
Operating junction & storage temperature	T <sub>j</sub> , T <sub>storage</sub>	Continuous	-55175	°C	
Soldering temperature	T <sub>solder</sub>	Wave soldering leads	260	°C	
Mounting torque		M3 Screw	1	N-m	

Notes:

\* EAS of 67 mJ is based on starting Tj = 25°C, L = 1.0 mH, IAS = 11.58 A, V = 50 V.

\*\* Typical Rth<sub>JC</sub> used

\*\*\* Per Device

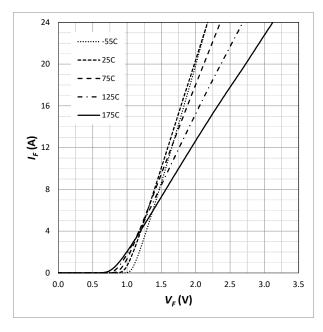
Characteristics Per Leg	Symbol	Conditions	Values			Unit
	Symbol		min.	typ.	max.	Onit
DC blocking voltage	V <sub>DC</sub>	T <sub>j</sub> =25 °C	650	-	-	V
		I <sub>F</sub> =10A, T <sub>j</sub> =25 °C	-	1.50	1.60	
Diode forward voltage	V <sub>F</sub>	I <sub>F</sub> =10A, T <sub>j</sub> =125 °C	-	1.59	-	V
		I <sub>F</sub> =10A, T <sub>j</sub> =175 °C	-	1.72	2.20	
Reverse current		V <sub>R</sub> =650V, T <sub>j</sub> =25 °C	-	2	25	μΑ
	1	V <sub>R</sub> =650V, T <sub>j</sub> =125 °C	-	11	-	
		V <sub>R</sub> =650V, T <sub>j</sub> =175 °C	-	36	250	
Total capacitive charge	Q <sub>C</sub>	V <sub>R</sub> =400V, T <sub>j</sub> =25 °C	-	26	-	nC
		V <sub>R</sub> =1V, f=1 MHz	-	419	-	
Total capacitance	С	V <sub>R</sub> =200V, f=1 MHz	-	51	-	pF
		V <sub>R</sub> =400V, f=1 MHz	-	43	-	]

### Electrical Characteristics, at T<sub>i</sub>=25 °C, unless otherwise specified

### **Thermal Characteristics**

Characteristics Per Leg	Symbol Conditions		Values			Unit
	Symbol	Conditions	min.	typ.	max.	onit
Thermal resistance, junction-case	$R_{thJC}$	-	-	1.54	2.1	°C/W

### **Typical Performance Per Leg**





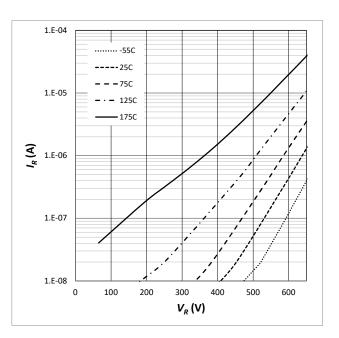
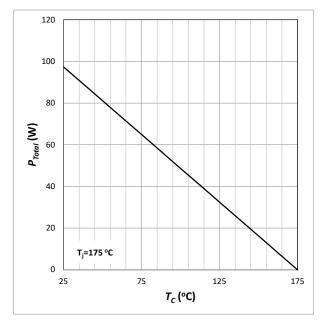


Fig. 2 Reverse Characteristics (parameterized on T<sub>i</sub>)



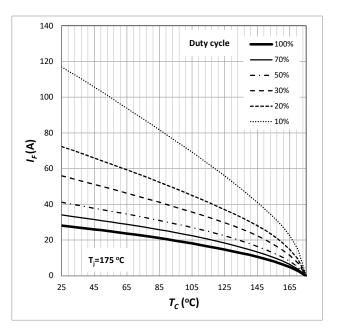
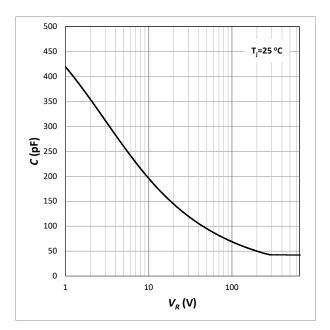


Fig. 3 Power Derating

Fig. 4 Current Derating



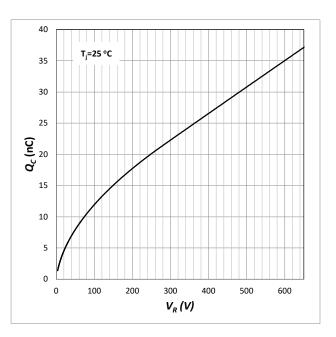
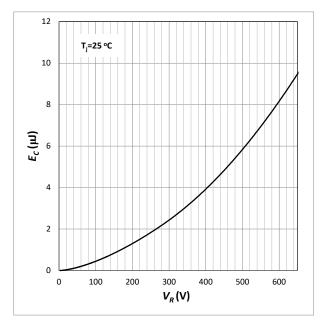


Fig. 5 Capacitance

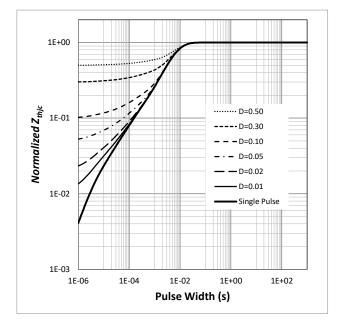
Fig. 6 Capacitive Charge

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## GP3D020A065U

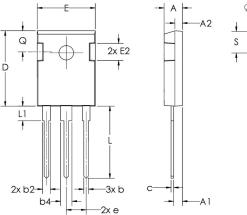


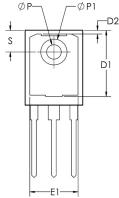






### Package Dimensions TO-247-3L





Sum	Millimeters		Inches		
Sym	Min	Max	Min	Max	
Α	4.70	5.31	0.185	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b2	1.65	2.39	0.065	0.094	
b4	2.59	3.43	0.102	0.135	
С	0.38	0.89	0.015	0.035	
D	20.80	21.46	0.819	0.845	
D1	13.08	17.65	0.515	0.695	
D2	0.51	1.35	0.020	0.053	
E	15.49	16.26	0.610	0.640	
E1	13.46	14.16	0.530	0.557	
E2	3.43	5.49	0.135	0.216	
е	5.44 BSC 0.2		0.214	BSC	
L	19.81	20.32	0.780	0.800	
L1	4.10	4.50	0.161	0.177	
ØP	3.56	3.66	0.140	0.144	
ØP1	7.06	7.39	0.278	0.291	
Q	5.39	6.20	0.212	0.244	
S	6.04	6.30	0.238	0.248	

#### Notes

#### **RoHS Compliance**

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented March, 2013. RoHS Declarations for this product can be obtained from the Product Documentation sections of www.SemiQ.com.

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